Diode Semiconductor Device - Page 1 of 1



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| Inclos | ure Material: |
|---------|--|
| Glass | |
| Overa | II Length: |
| 0.200 | inches |
| Termi | nal Length: |
| 1.000 | inches |
| Overa | II Diameter: |
| 0.090 | inches |
| Funct | ion For Which Designed: |
| Voltag | e regulator |
| Mount | ting Method: |
| Termir | nal |
| Featu | res Provided: |
| Herme | atically sealed case |
| Semic | conductor Material: |
| Silicor | |
| Voltag | ge Rating In Volts Per Characteristic: |
| 7.5 re | egulator voltage |
| Voltag | ge Tolerance In Percent: |
| -1.0/+′ | 1.0 |
| Curre | nt Rating Per Characteristic: |
| 810.00 |) milliamperes source cutoff current horsepower metric |
| Power | Rating Per Characteristic: |
| 400.0 | milliwatts small-signal input power, common-collector preset |
| Maxin | num Operating Tempurature Per Measurement Point: |
| 175.0 | degrees celsius ambient air |
| Termi | nal Type And Quantity: |
| 2 unin | sulated wire lead |
| Shelf | Life: |
| N/a | |
| Unit C | of Measure: |
| | |
| Demil | itarization: |
| No | |
| Fiig: | |
| A110a | 0 |